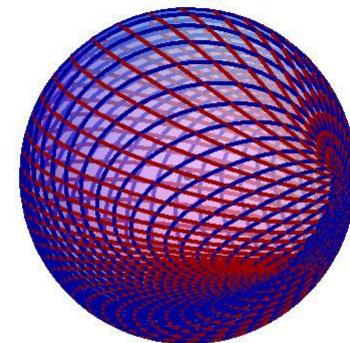


# **Topological Physics in Band Insulators**

**Gene Mele  
University of Pennsylvania**



# **Lecture Topics:**

- 1. Topological Band Insulators (mostly 1D)**
- 2. Topological Insulators (2D and 3D)**
- 3. Low energy models for real materials**
- 4. Wannier representations and band projectors**



# **Collaborators:**

**Charlie Kane**

**David DiVincenzo**

**Liang Fu**

**Petr Kral**

**Andrew Rappe**

**Michael Rice**

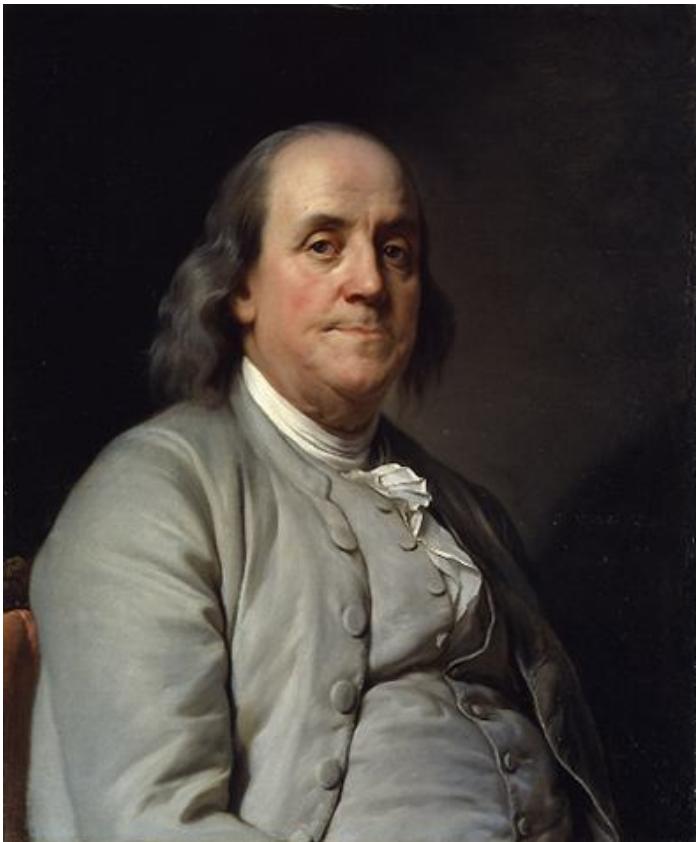
**Saad Zaheer**

**Fan Zhang**



# Electronic States of Matter

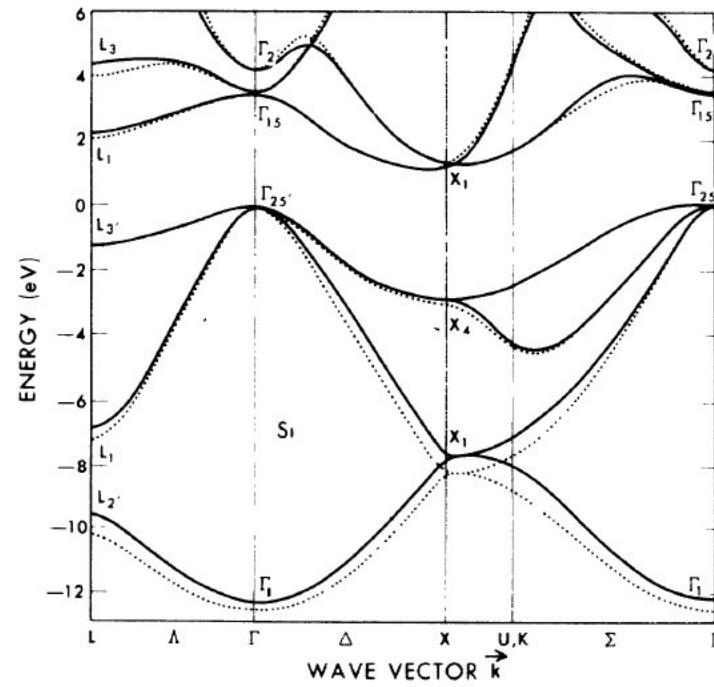
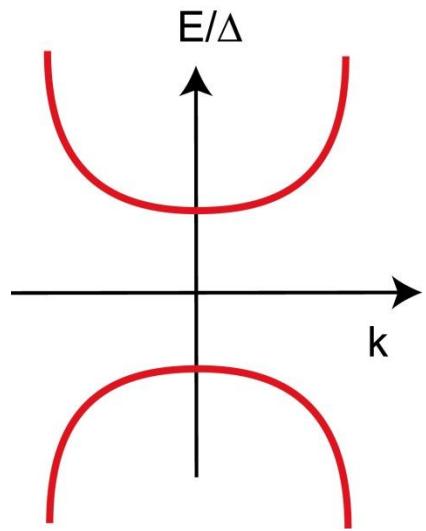
Benjamin Franklin (University of Pennsylvania)



*That the Electrical Fire freely removes from Place to Place in and thro' the Substance of a Non-Electric, but not so thro' the Substance of Glass. If you offer a Quantity to one End of a long rod of Metal, it receives it, and when it enters, every Particle that was before in the Rod pushes it's Neighbour and so on quite to the farther End where the Overplus is discharg'd... But Glass from the Smalness of it's Pores, or stronger Attraction of what it contains, refuses to admit so free a Motion. A Glass Rod will not conduct a Shock, nor will the thinnest Glass suffer any Particle entring one of it's Surfaces to pass thro' to the other.*



# Band Insulators (orthodoxy)

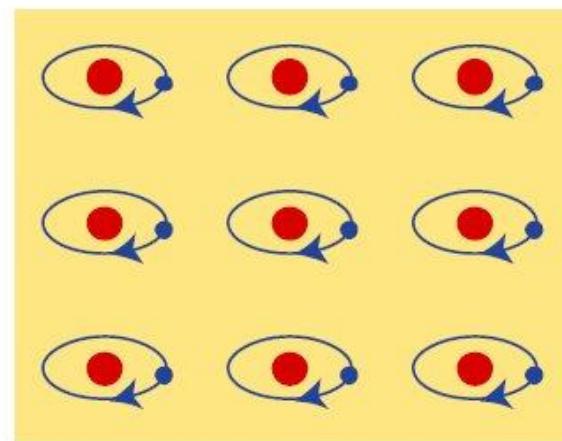
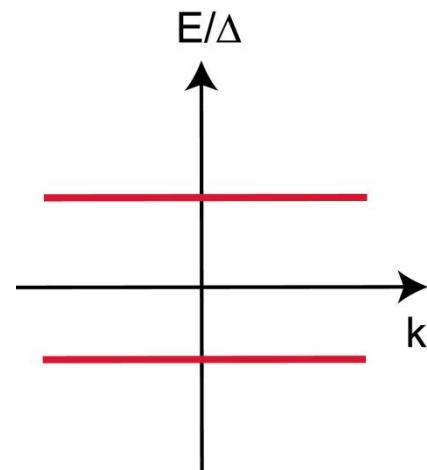


Examples: Si, GaAs,  $\text{SiO}_2$ , etc

Because of the “smallness of its pores”



# Band Insulators (atomic limit)



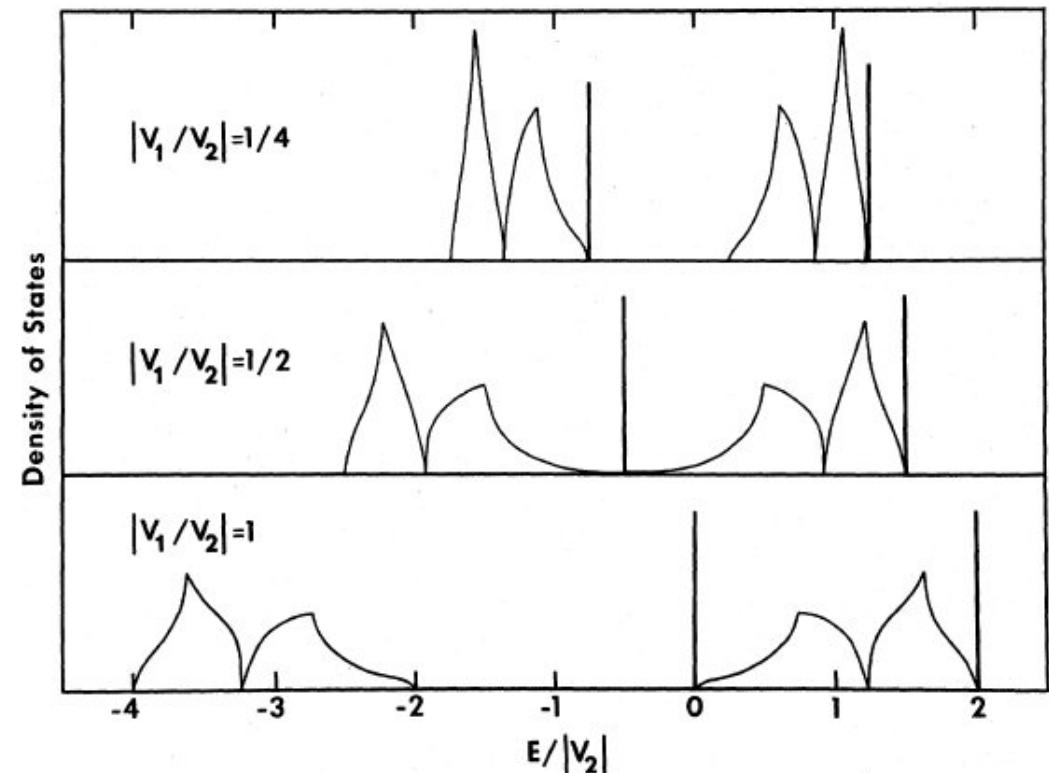
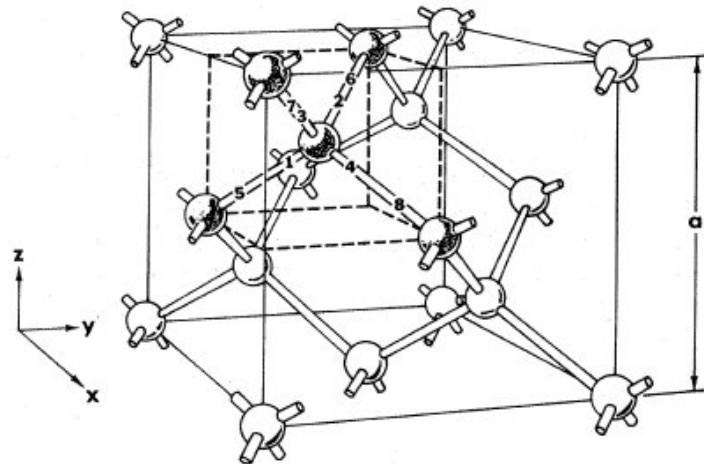
Examples: atoms, molecular crystals, etc.

“Attraction for what it contains”



# Transition from covalent to atomic limits

Tetrahedral semiconductors

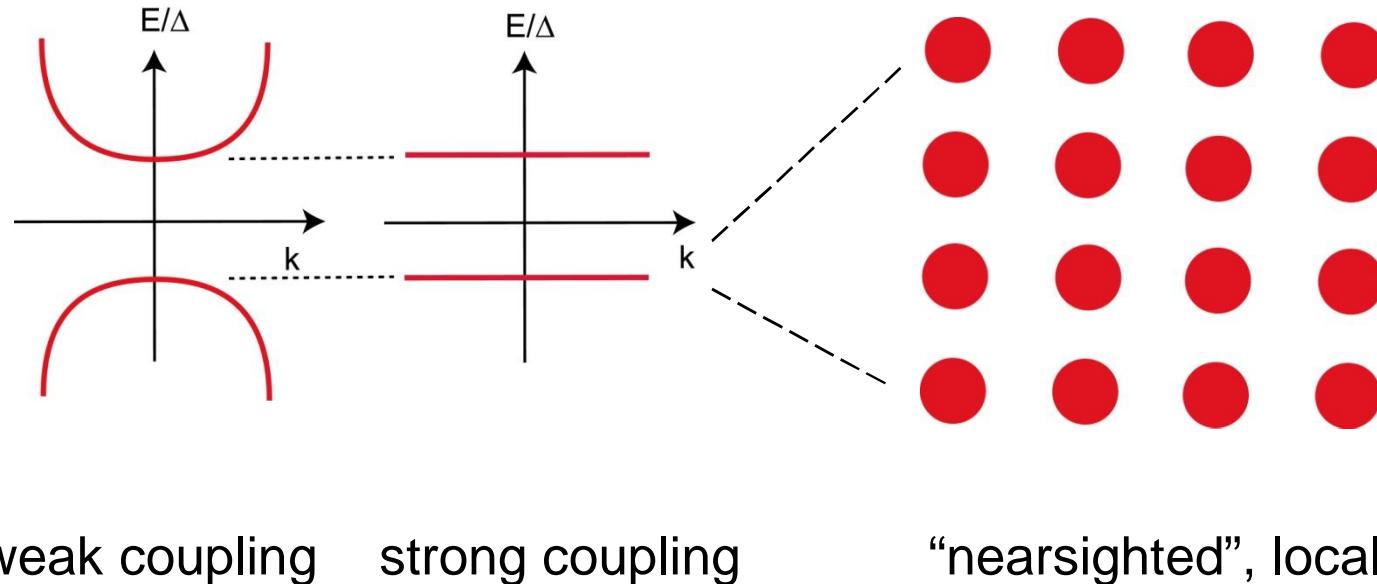


Weaire & Thorpe (1971)



## Modern view: Gapped electronic states are equivalent

Kohn (1964): insulator is exponentially insensitive to boundary conditions



Postmodern: Gapped electronic states are distinguished by topological invariants



# Topological States

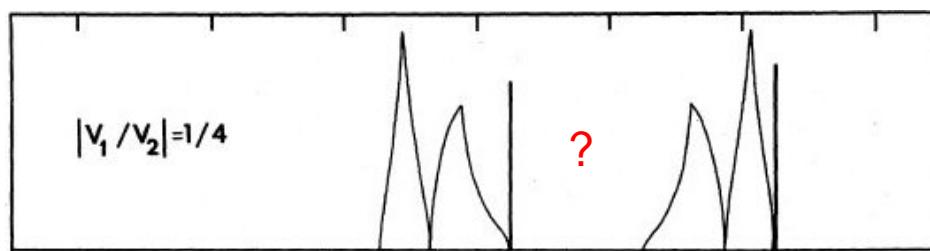
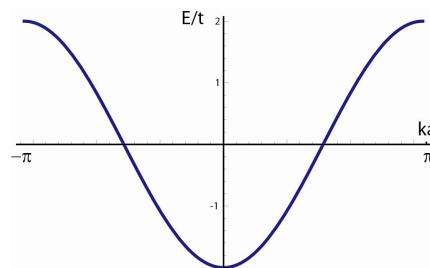
Topological classification of valence manifold

Examples in 1D lattices: variants on primer



$$H = t \sum_n c_{n+1}^\dagger c_n + c_n^\dagger c_{n+1}$$

$$= \sum_k 2t \cos ka$$



# Cell Doubling (Peierls, SSH)



$$H(k) = \begin{pmatrix} 0 & t_1 + t_2 e^{-2ika} \\ t_1 + t_2 e^{2ika} & 0 \end{pmatrix}$$

smooth gauge  $H(k + \frac{2\pi}{2a}) = H(k)$

$$H(k) = \vec{h}(k) \cdot \vec{\sigma} \quad \left\{ \begin{array}{l} h_x = t_1 + t_2 \cos 2ka \\ h_y = t_2 \sin 2ka \\ h_z = 0 \end{array} \right.$$

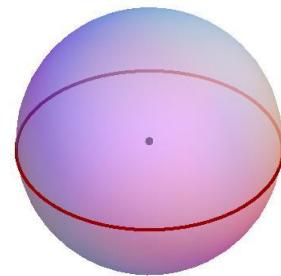
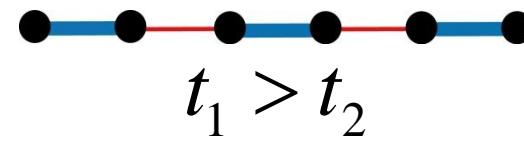
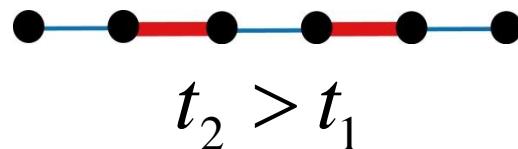
Su, Schrieffer, Heeger (1979)



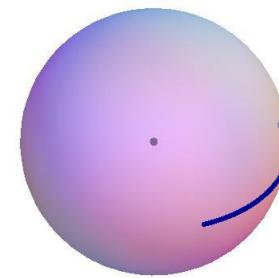
# Project onto Bloch Sphere

$$H = |h(k)| \vec{d}(k) \cdot \vec{\sigma}$$

$$|h(k)| = \sqrt{t_1^2 + t_2^2 + 2t_1t_2 \cos 2ka}$$



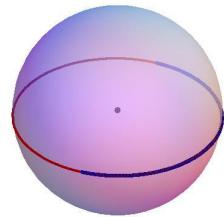
Closed loop



Retraced path



# Formulation as a Berry's Phase



$$\psi_- = \frac{1}{\sqrt{2}} \begin{pmatrix} 1 \\ -e^{i\phi} \end{pmatrix}; \psi_+ = \frac{1}{\sqrt{2}} \begin{pmatrix} 1 \\ e^{i\phi} \end{pmatrix}$$

$$\text{Im} \left\langle \psi_\lambda \mid \frac{\partial \psi_\lambda}{\partial \lambda} \right\rangle = \frac{\partial \gamma}{\partial \lambda} \quad \psi_\lambda = e^{i\gamma} |\psi_\lambda|$$

$$\gamma = \oint \frac{\partial \gamma}{\partial \phi} d\phi \quad \begin{cases} \pi: \text{ A phase} & \text{Closed loop} \\ 0: \text{ B phase} & \text{Retraced path} \end{cases}$$

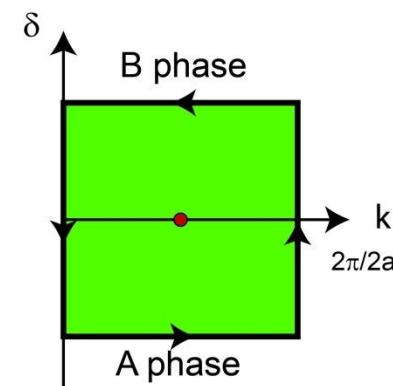


# Formulation using Electric Polarization

$$\vec{h}(k) \Rightarrow \vec{h}(k, \delta)$$

$$\delta = t_1 - t_2$$

$$\vec{\lambda} = (k, \delta)$$



$$\gamma_A - \gamma_B = \text{Im} \oint \left\langle \psi \left| \frac{\partial \psi}{\partial k} \right. \right\rangle dk$$

$\underbrace{\hspace{10em}}$

$A_k : \text{ connection}$

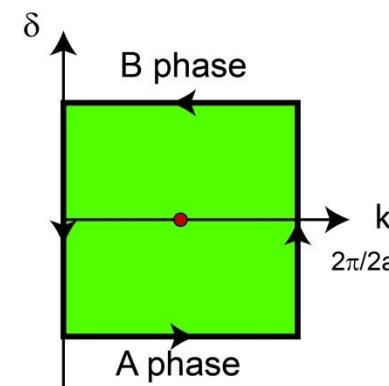


# Stokes Integral of Berry Curvature

$$\vec{h}(k) \Rightarrow \vec{h}(k, \delta)$$

$$\delta = t_1 - t_2$$

$$\vec{\lambda} = (k, \delta)$$



$$\gamma_A - \gamma_B = \int_S \text{Im} \left\{ \left\langle \frac{\partial \psi}{\partial \delta} \mid \frac{\partial \psi}{\partial k} \right\rangle - \left\langle \frac{\partial \psi}{\partial k} \mid \frac{\partial \psi}{\partial \delta} \right\rangle \right\} d^2 \lambda$$

$F_{k,\delta}$  Berry curvature

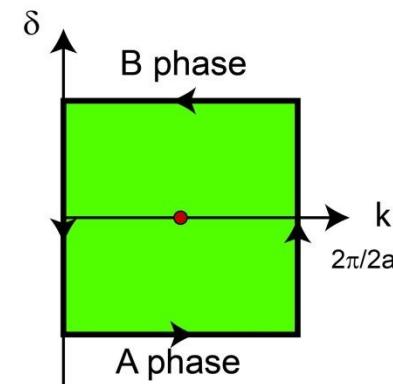


# Polarization from adiabatic current

$$\vec{h}(k) \Rightarrow \vec{h}(k, \delta)$$

$$\delta = t_1 - t_2$$

$$\vec{\lambda} = (k, \delta)$$



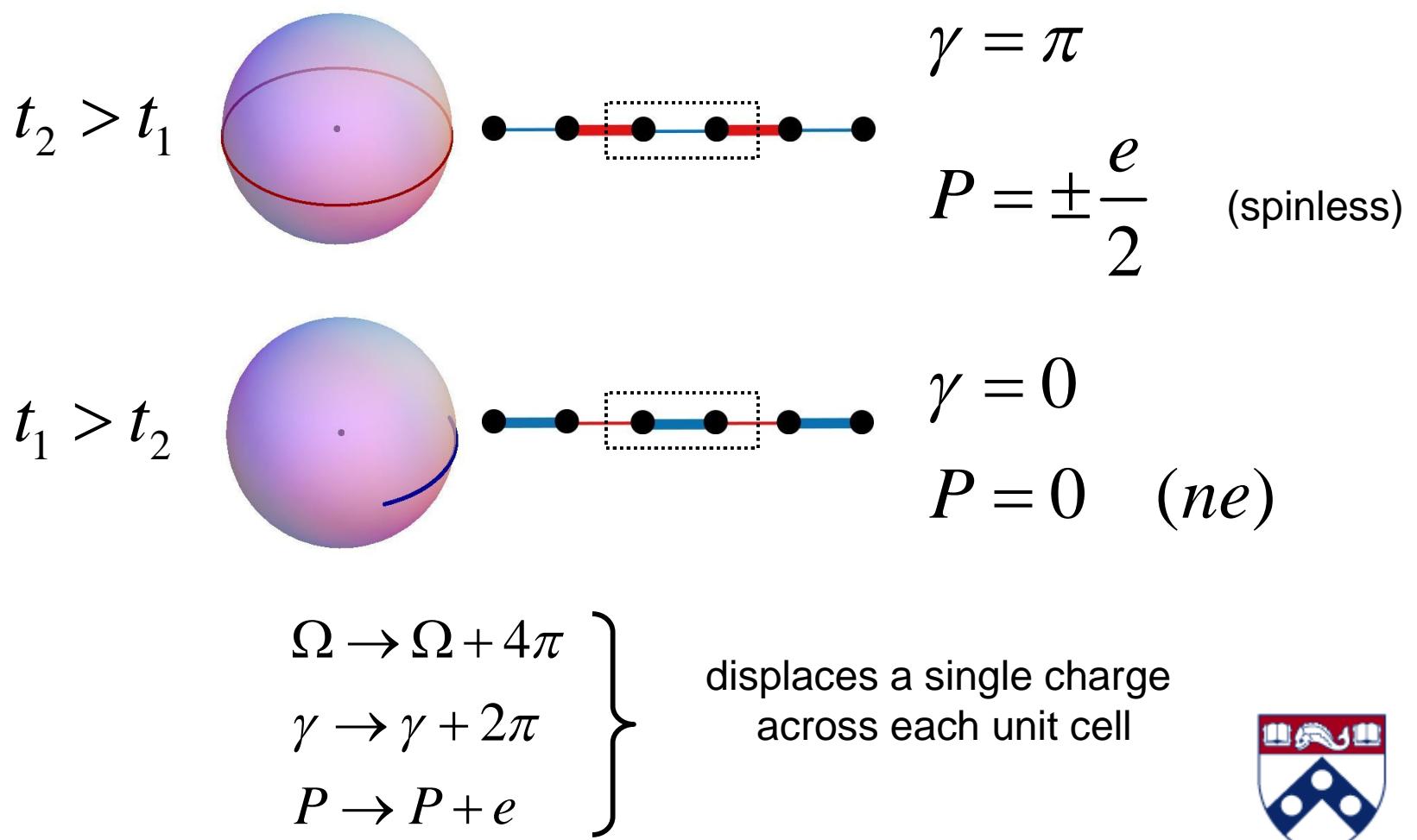
$$\gamma_A - \gamma_B = \begin{cases} \frac{\Omega}{2} & \Omega : \text{Solid angle swept out} \\ \frac{2\pi}{e} \int dt \langle J \rangle_\delta & = \frac{2\pi}{eL} (P_A - P_B) \end{cases}$$

$\langle J \rangle_\delta$  Ground state current (via Kubo)

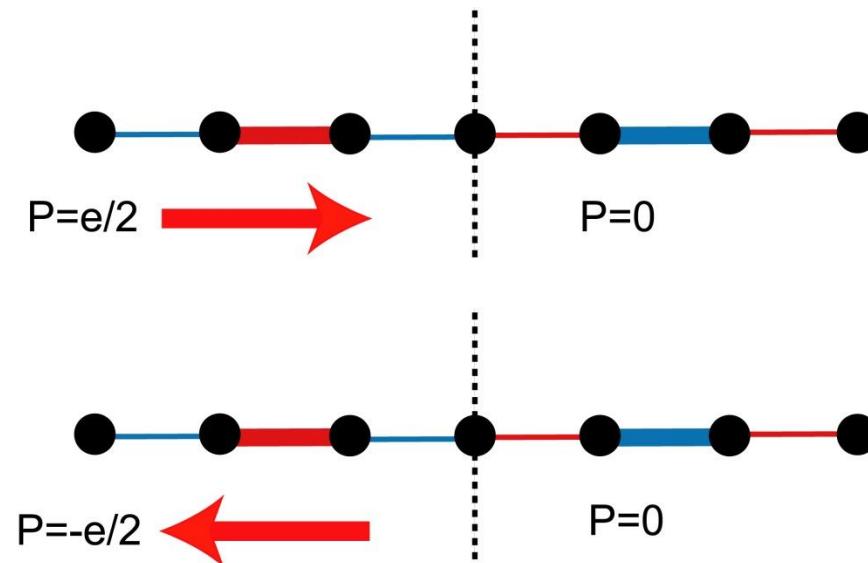
King-Smith and Vanderbilt (1993)



# Example: dimerized 1D lattice



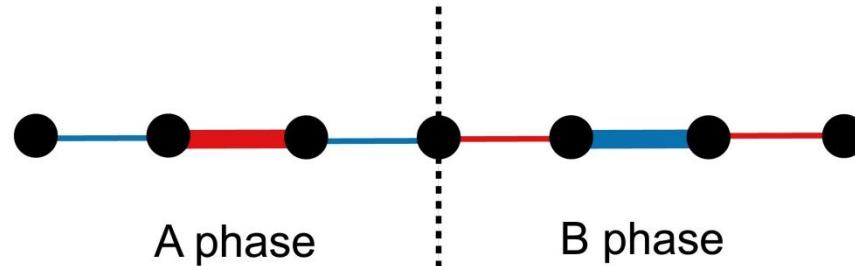
# Topological Domain Walls



$$Q^* = \pm \frac{e}{2} \quad (\text{spinless})$$



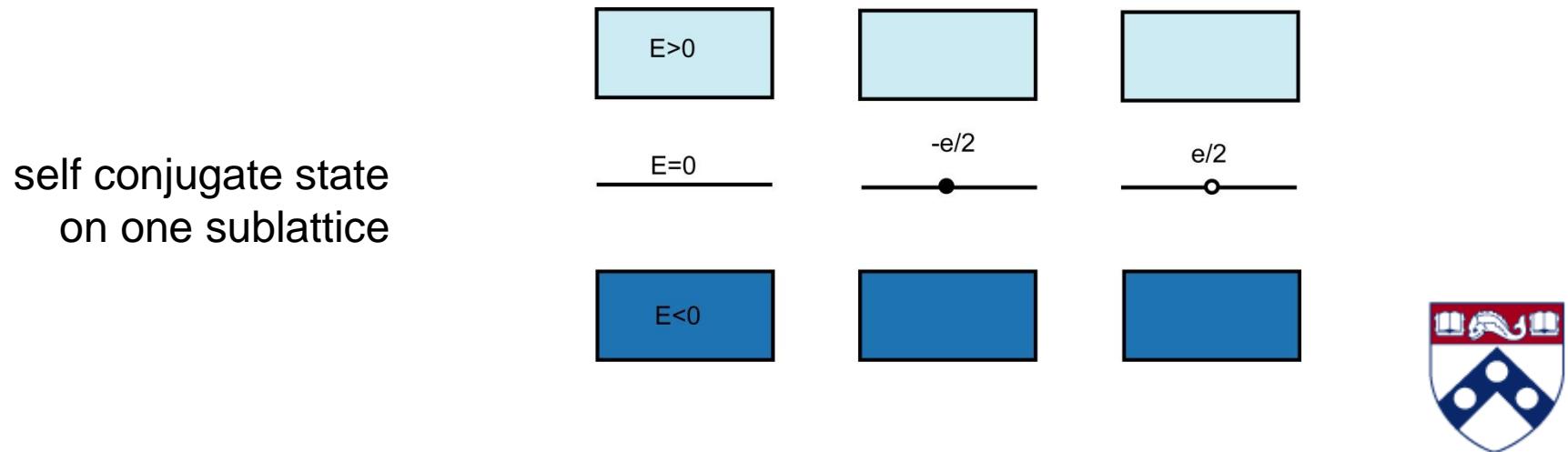
# State Counting



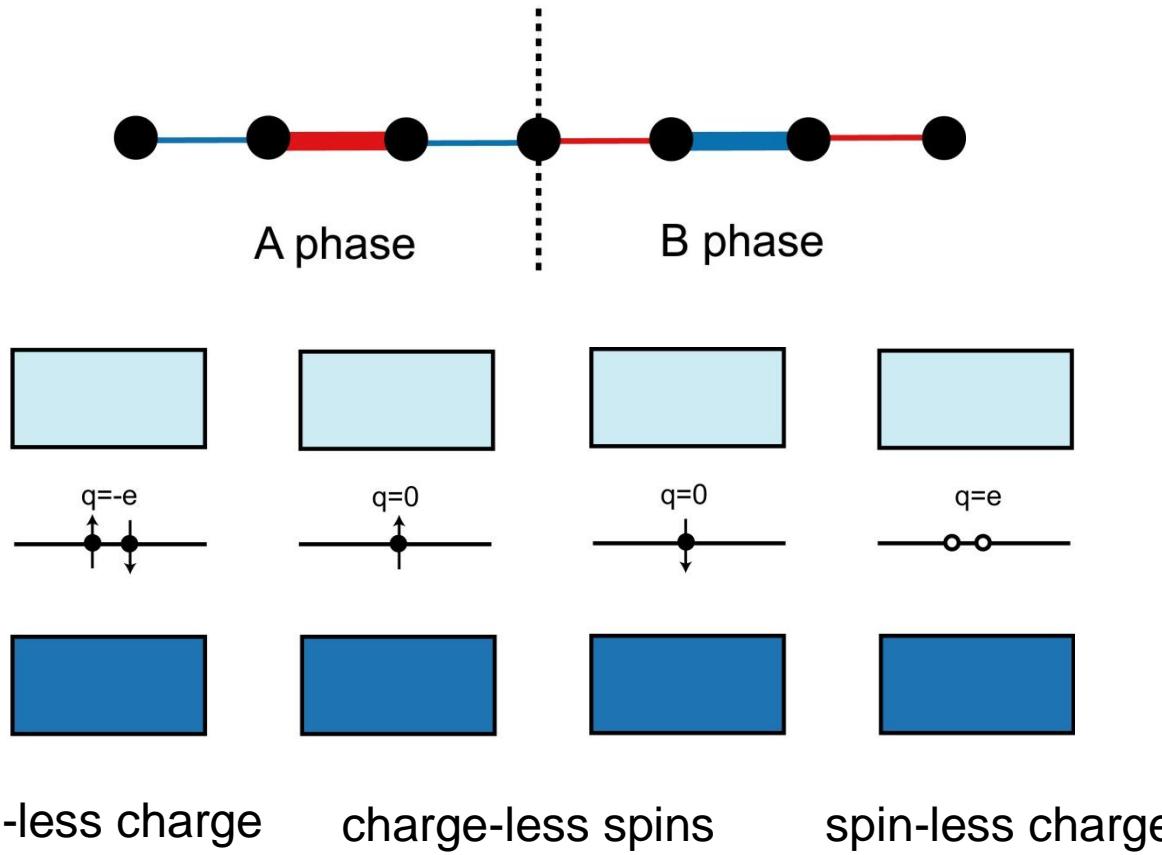
Particle-hole symmetry

$$C H C^{-1} = -H; \quad C = \sum_n (-1)^n c_n^\dagger c_n$$

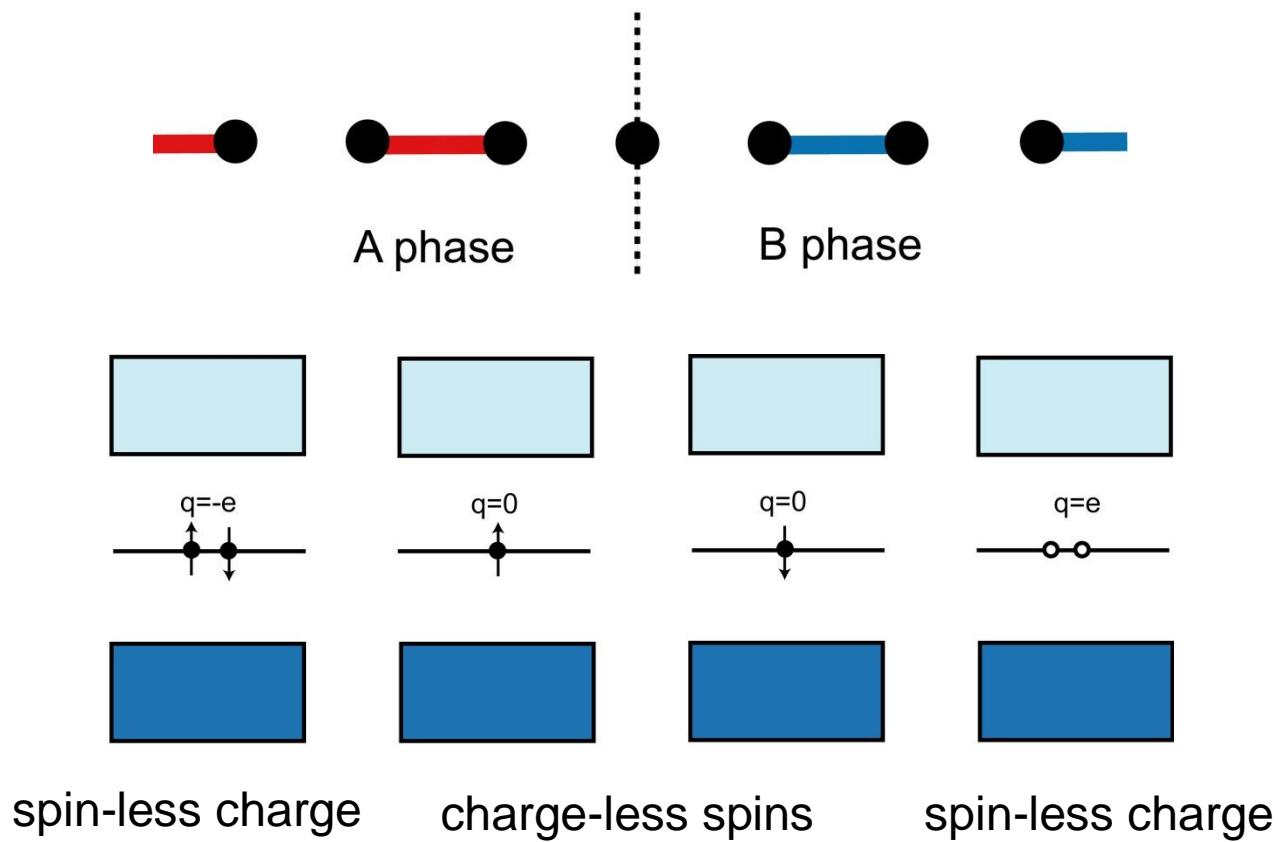
on odd numbered chain



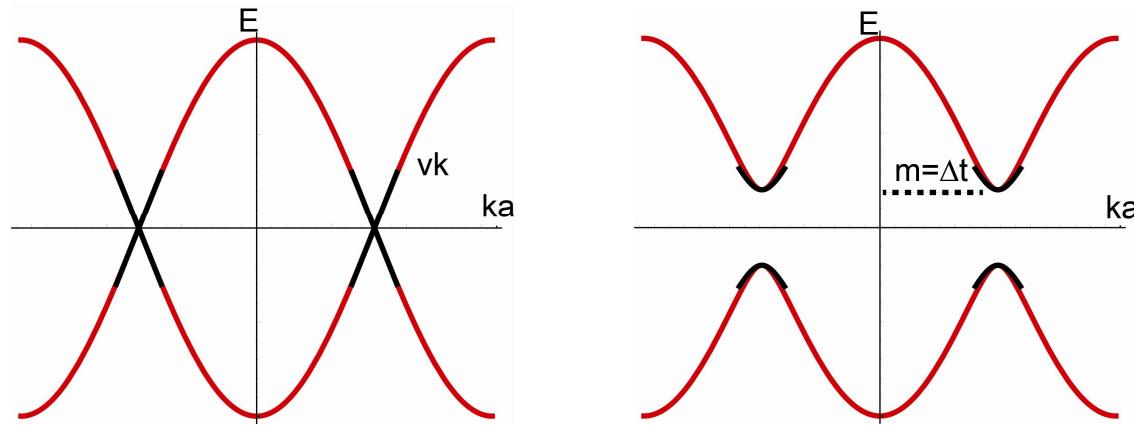
# ...with spin



# ...for strong coupling



# Continuum Model



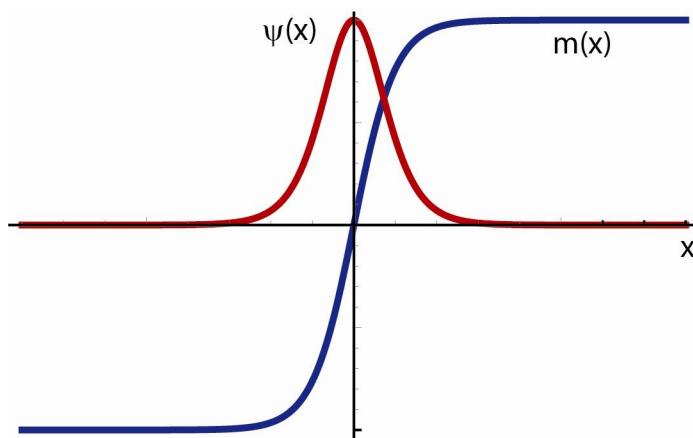
$$\begin{pmatrix} e^{-\frac{i\pi}{4}} & 0 \\ 0 & e^{\frac{i\pi}{4}} \end{pmatrix} H \left( \frac{\pi}{2a} + q \right) \begin{pmatrix} e^{\frac{i\pi}{4}} & 0 \\ 0 & e^{-\frac{i\pi}{4}} \end{pmatrix} = -i\nu_F \hat{\sigma}_x \frac{\partial}{\partial x} + m \hat{\sigma}_y$$

$$E = \pm \sqrt{m^2 + \nu^2 q^2}$$

“relativistic bands” back-scattered by mass  $m = t_1 - t_2$



# Mass inversion at domain wall



Sublattice-polarized E=0 bound state

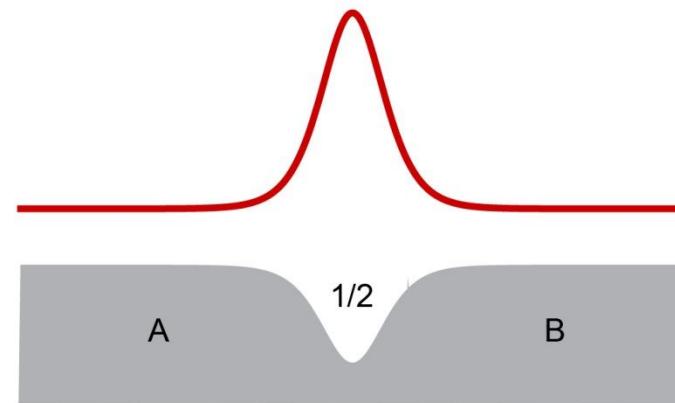
$$\psi(x) = A \exp \left[ - \int_0^x \frac{m(x)}{\nu} dx \right] \begin{pmatrix} 0 \\ 1 \end{pmatrix} \quad \xi = \frac{\hbar v}{m}$$

Jackiw-Rebbi (1976)

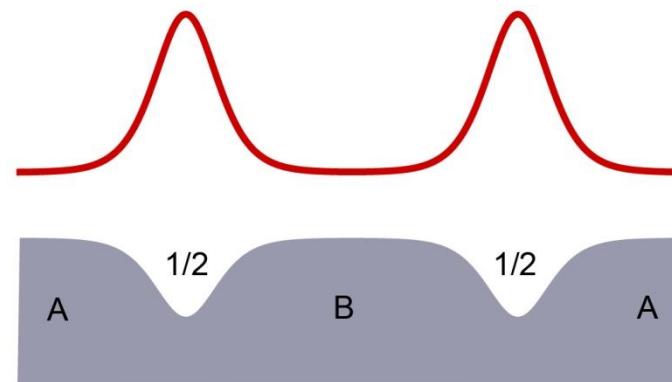


# Backflow of filled Fermi sea

Fractional depletion  
of filled Fermi sea



Occurs in pairs  
(topologically connected)



# Heteropolar Lattice



$$H = t \sum_n c_{n+1}^\dagger c_n + c_n^\dagger c_{n+1}$$
$$+ \delta \sum_n (-1)^n (c_{n+1}^\dagger c_n + c_n^\dagger c_{n+1}) + \Delta \sum_n (-1)^n c_n^\dagger c_n$$

$\uparrow$  modulate bond strength       $\uparrow$  staggered potential

Rice and GM (1982)

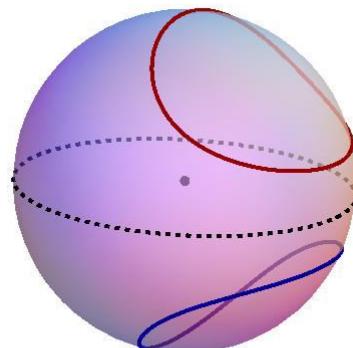


# On Bloch Sphere

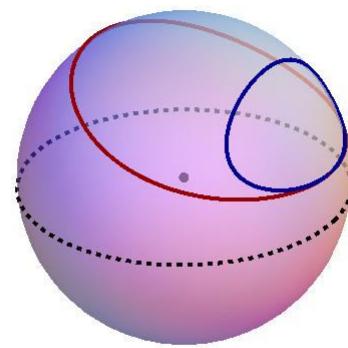


$$H(k) = \vec{h}(k) \cdot \vec{\sigma} \quad \left\{ \begin{array}{l} h_x = t + \delta + (t - \delta) \cos 2ka \\ h_y = (t - \delta) \sin 2ka \\ h_z = \Delta \end{array} \right.$$

$\Delta > 0$



$\Delta < 0$



$\delta > 0$

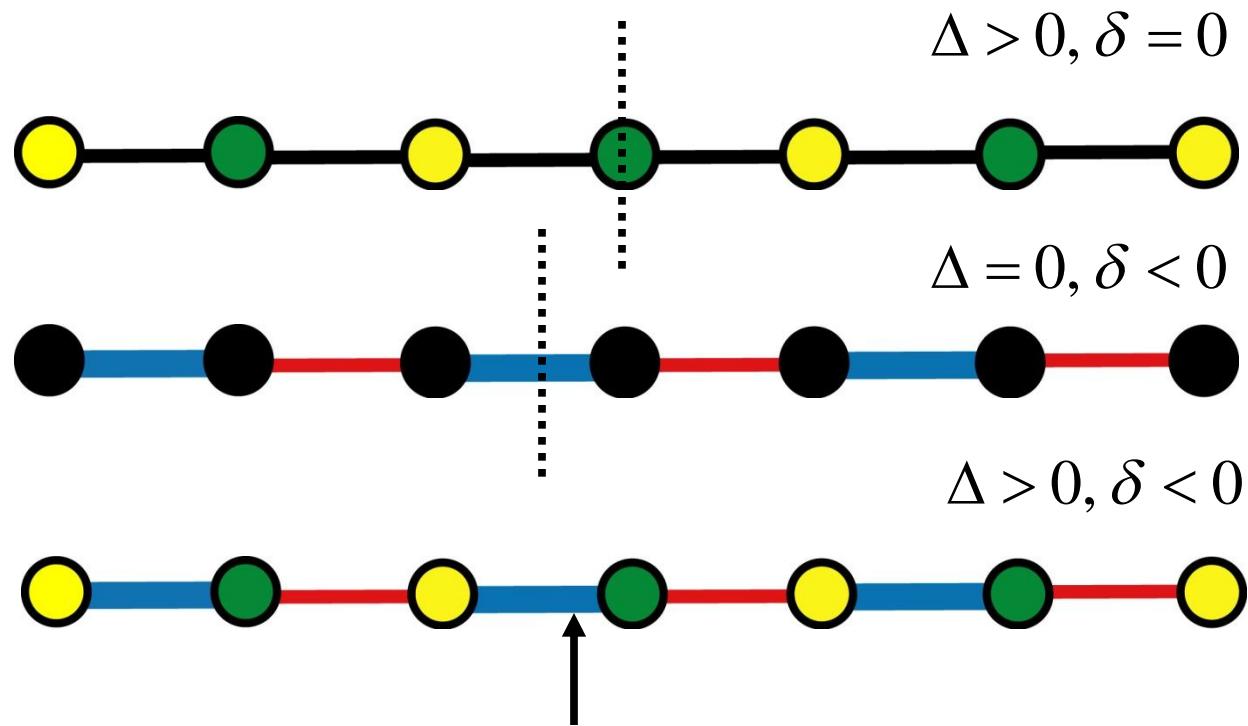
$\delta > 0$

$\delta < 0$

$\Delta > 0$



# High symmetry cases



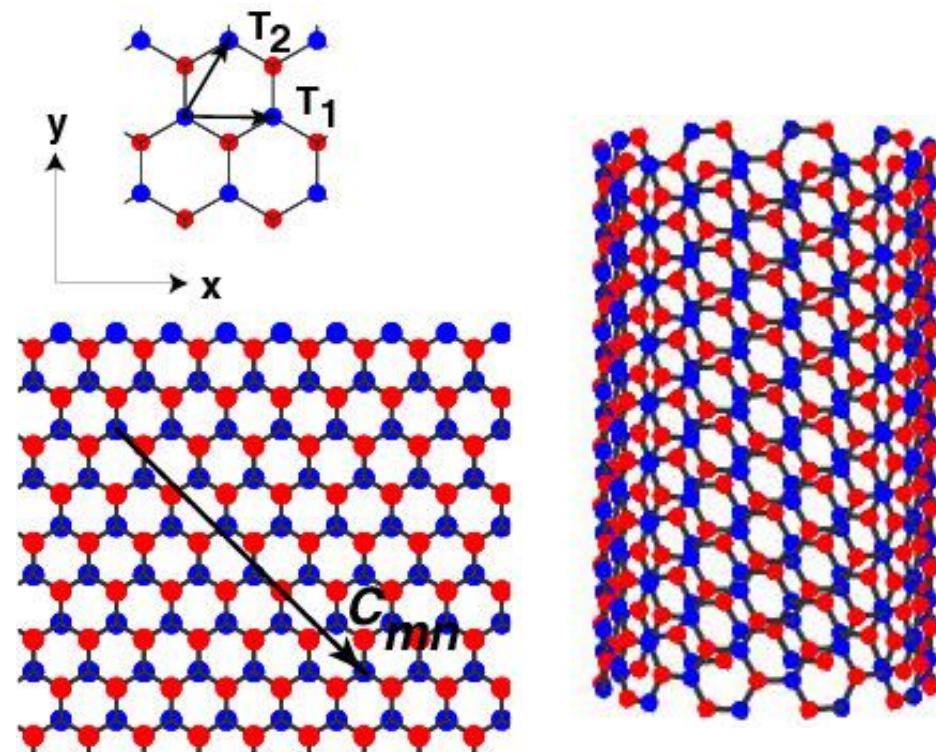
Continuously tunes the domain wall charge

$$Q^* = ne + Q_v(\delta, \Delta)$$

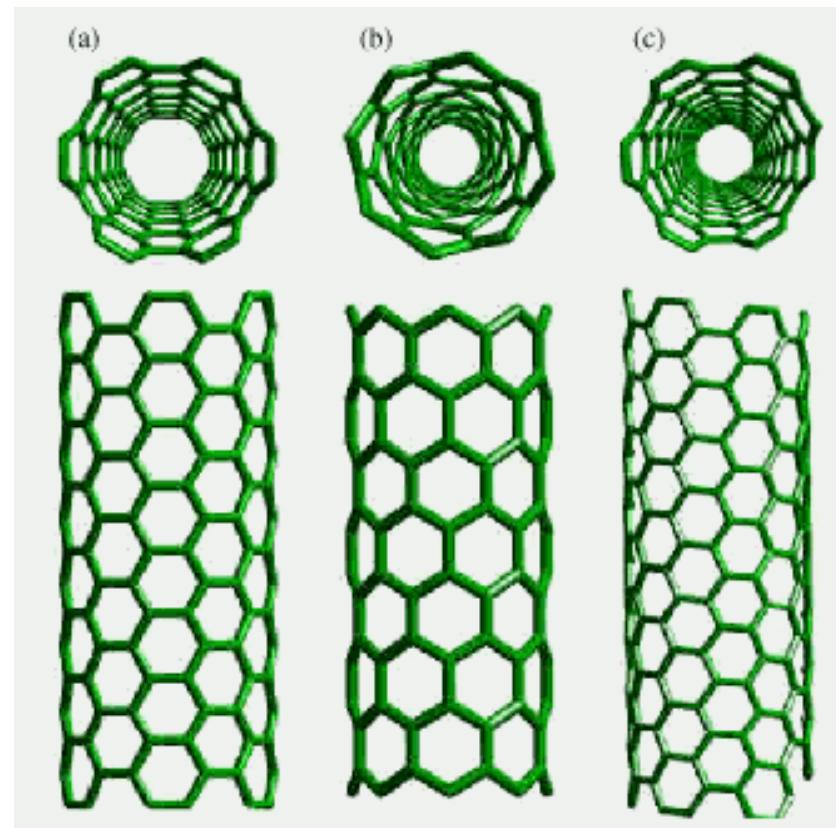


# Heteropolar NT's of Boron Nitride

BN is the III-V variant of graphene. The B and N occupy different sublattices -- this lowers the symmetry and leads to new physical effects

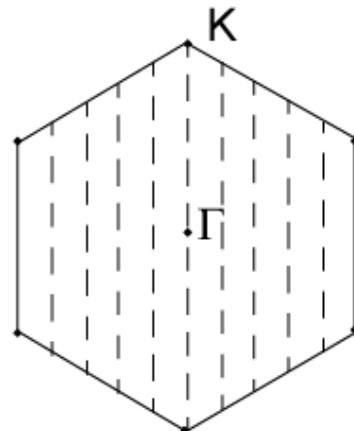


# Conducting v. Semiconducting Nanotubes

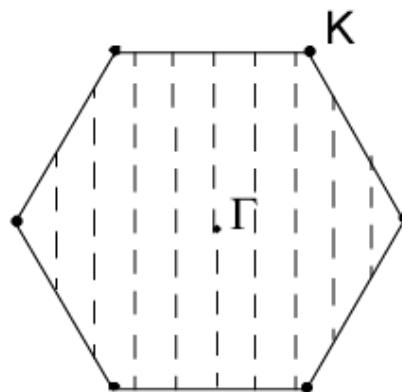


# Conducting v. Semiconducting Nanotubes

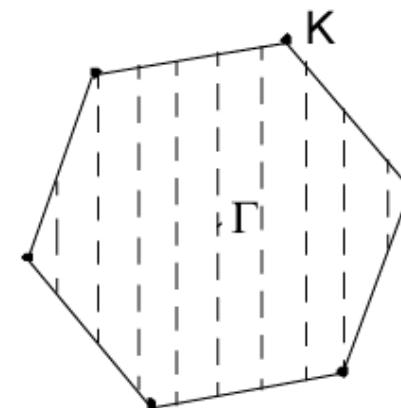
(5,5) Armchair Tube  
Metal



(5,0) Zigzag Tube  
Semiconductor



(5,-1) Tube  
Metal  
(small-gap SC)



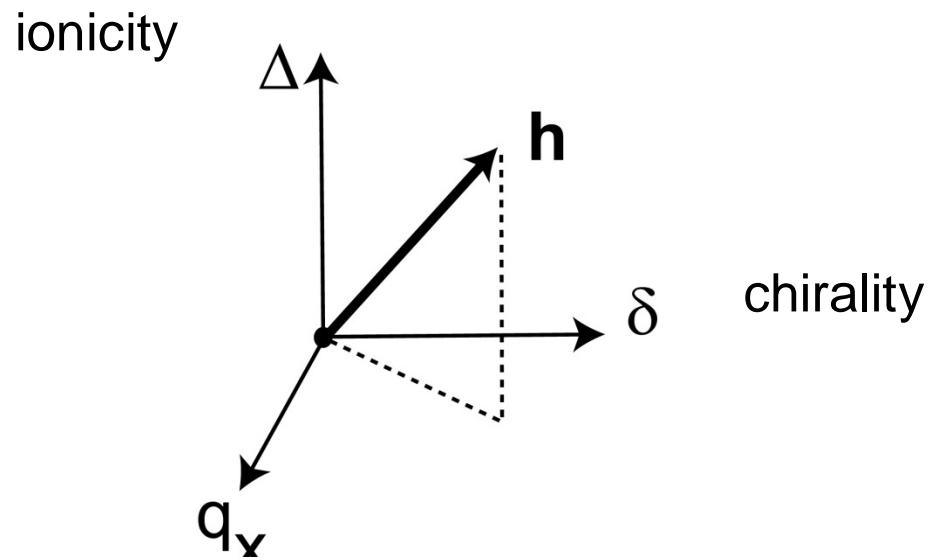
$m=n$

$\text{mod}(m-n,3) = \pm 1$

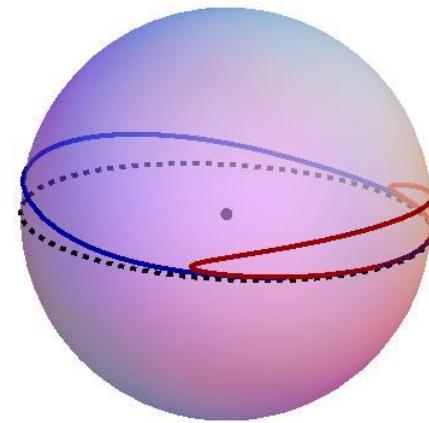
$\text{mod}(m-n,3) = 0, m \neq n$



# Nanotube Polarization



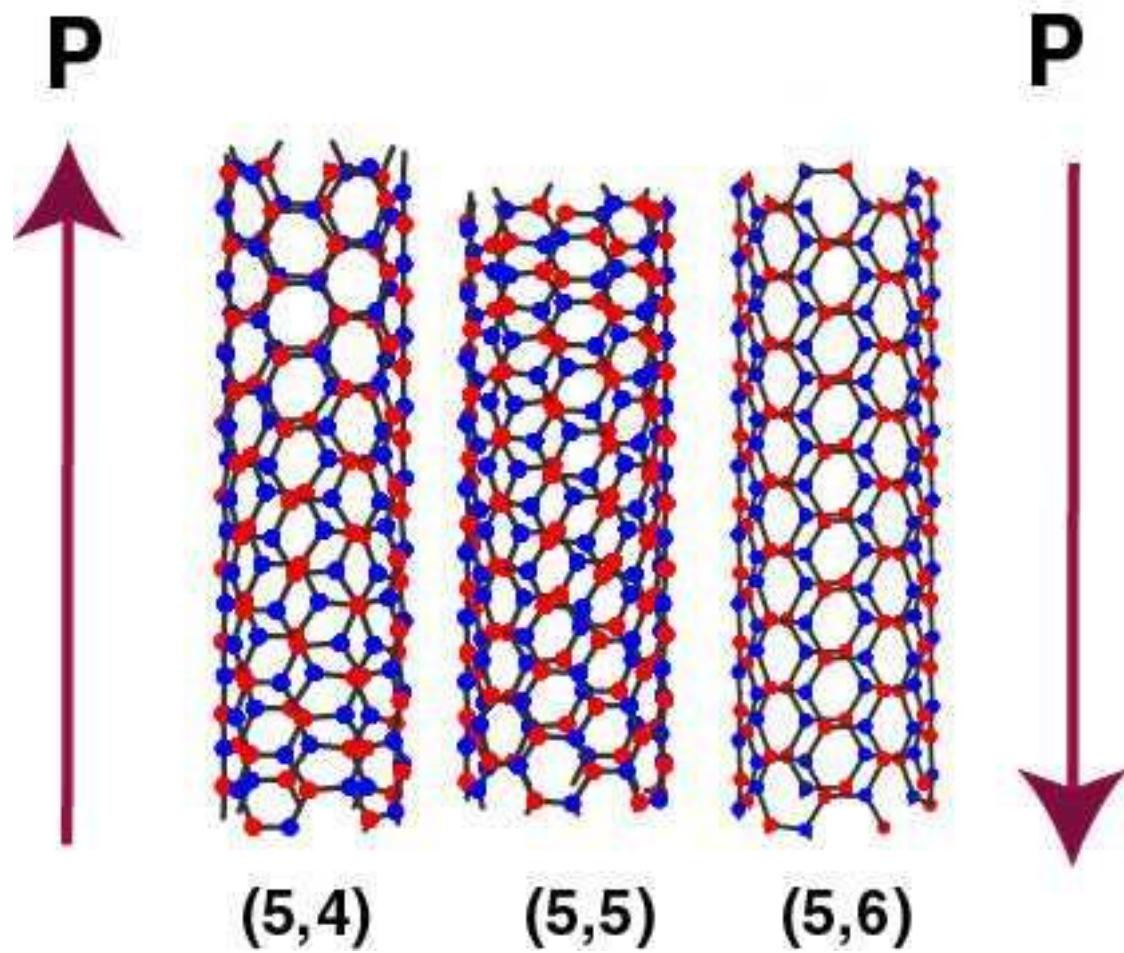
chirality



$$P = e \frac{\gamma}{2\pi}, \quad \frac{\pm e}{2} - e \frac{\gamma}{2\pi}$$

$$H(q_x, \delta, \Delta) = \Psi^\dagger \begin{pmatrix} \Delta & \hbar v_F (q_x - i\delta) \\ \hbar v_F (q_x + i\delta) & -\Delta \end{pmatrix} \Psi$$

# Nanotube Polarization

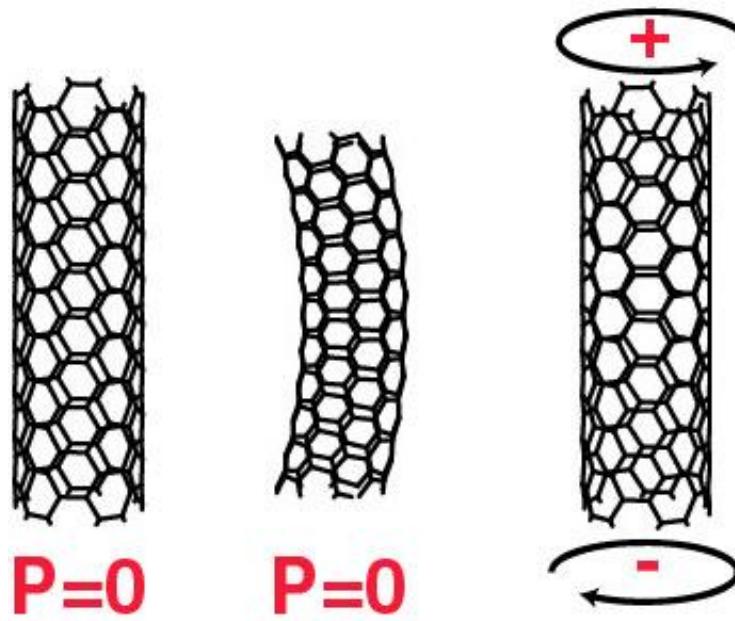


GM and P. Kral (2002)



# Polarization and elastic strain

(twist is a gauge field that modulates  $\delta$ )

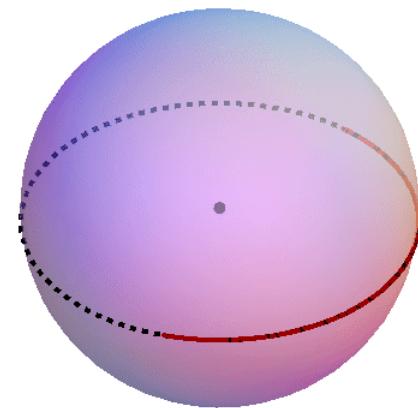


Heteropolar NT's are molecular piezoelectrics

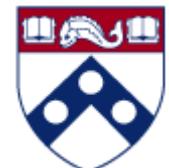
GM and P. Kral (2002)

# **One Parameter Cycle**

e.g. periodic tube torsion modulates P

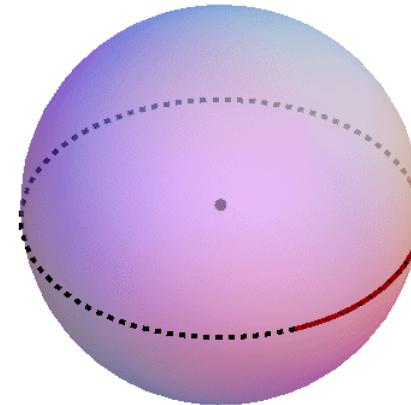


Bond strengths are modulated periodically  
in a reversible cycle



# Two Parameter Cycle

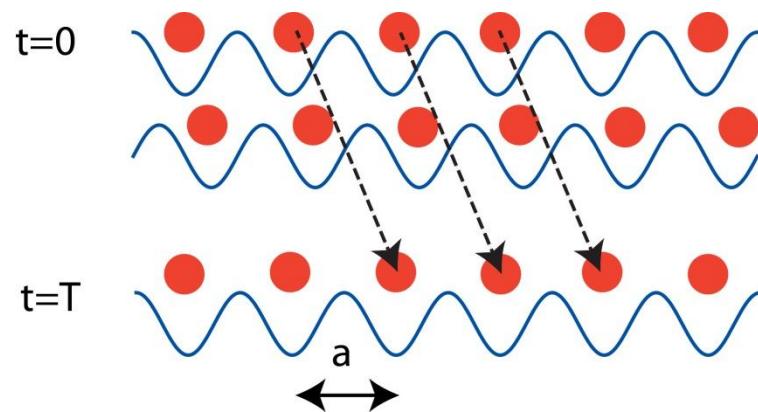
ionicity and chirality are  
nonreciprocal potentials



Nonreciprocal cycle enclosing a point of degeneracy with  
Chern number:

$$n = \frac{1}{4\pi} \int_S dk dt \left[ \vec{d}(k, t) \cdot \left( \partial_k \vec{d} \times \partial_t \vec{d} \right) \right]$$


# Thouless Charge Pump



$$H(k, t+T) = H(k, t)$$

with no gap closure on path

$$\Delta P = \frac{e}{2\pi} \left( \int_{t+T} A_k \, dk - \int_t A_k \, dk \right)$$

$$= \frac{e}{2\pi} \int_S F_{k,t} \, dk \, dt = ne$$

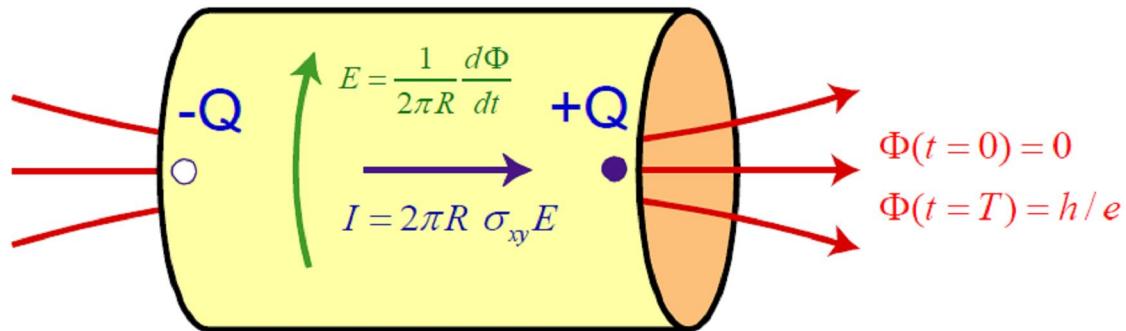
$n=0$  if potentials commute

Thouless (1983)



# Quantized Hall Conductance

Adiabatic flux insertion through 2DEG on a cylinder:



$$2\pi R \int dt \langle j \rangle = 2\pi R \int dt \sigma_{xy} E = Q$$

$$\sigma_{xy} \frac{h}{e} = Q = ne$$

$$\sigma_{xy} = n \frac{e^2}{h}$$

TKNN invariant  
is the Chern number

Laughlin (1981), Thouless et al. (1983)



## **Some References:**

Berry Phases: Di Xiao, M-C Chang, Q. Niu  
Rev. Mod. Phys. 82, 1959 (2010)

SSH Model: A.J. Heeger, S. Kivelson, J.R. Schrieffer  
and W-P Su, Rev. Mod. Phys. 60, 781 (1988)

Heteropolar One Dimensional Lattice: M. J. Rice  
and E.J. Mele, Phys. Rev. Lett. 49, 1455 (1982)

Heteropolar Nanotubes: E.J. Mele and P. Kral  
Phys. Rev. Lett. 88, 05603 (2002)

